



BFG135AE6327XT Information



For Reference Only

Part Number BFG135AE6327XT **Manufacturer** Infineon Technologies

Category Discrete Semiconductor Products
Transistors - Bipolar (BJT) - RF

Description TRANS NPN RF 15V 150MA SOT223

Package TO-261-4, TO-261AA

For the pricing/inventory/lead time, please contact

us

Website: https://www.heisener.com E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









BFG135AE6327XT Specifications

Manufacturer Part Number	BFG135AE6327XT
Manufacturer	Infineon Technologies
Category	Discrete Semiconductor Products
	Transistors - Bipolar (BJT) - RF
Package	TO-261-4, TO-261AA
Series	-
Transistor Type	NPN
Voltage - Collector Emitter Breakdown (Max)	15V
Frequency - Transition	6GHz
Noise Figure (dB Typ @ f)	1.5dB ~ 2.6dB @ 900MHz ~ 1.8GHz
Gain	9dB ~ 14dB
Power - Max	1W
DC Current Gain (hFE) (Min) @ Ic, Vce	80 @ 100mA, 8V
Current - Collector (Ic) (Max)	150mA
Operating Temperature	-
Mounting Type	Surface Mount
Package / Case	TO-261-4, TO-261AA
Supplier Device Package	PG-SOT223-4
	Report errors?

BFG135AE6327XT Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

BFG135AE6327XT Payment Methods





















BFG135AE6327XT Shipping Methods













If you have any question about BFG135AE6327XT, please do not hesitate to contact us!

Website: https://www.heisener.com E-mail: salesdept@heisener.com